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a. Serial No.	f. Foreign Priority	k. Print Claim(s)	(p)PTO-1449			
b. Applicant(s)	g. Disclaimer	I. Print Fig.	g. PTOL-85b			
c. Continuing Data	h. Microfiche Appendix	m. Searched Column	r. Abstract			
.d. PCT	i. Title	n. PTO-270/328	s. Sheets/Figs			
e. Domestic Priority	j. Claims Allowed	o. PTO-892	t. Other			

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SPECIFICATION	MESSAGE There are two renumbered
a. Page Missing	claim 14 (original claims 18, 22) on the
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e. Illegible Text	or line through citation(s). Copy
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g. Brief Description	
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i. Appendix	
j. Amendments	
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# INFORMATION DISCLOSURE CITATION (Use several sheets if necessary)

Docket Number (Optional)
TWI-30400
Applicant(s)
Abdurrahman Sezginer et al.
Filing Date
February 12, 2002

Application Number
10/074,561

Group Art Unit
2877

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AG 62157295 06/23/1987 Japan H01L 21/30 Abstract  AH 0192 656 B1 05/23/1990 EPO G01B 11/06  AI WO 00/72093 A1 11/30/2000 PCT G03F 9/00	 		DATE	COUNTRY	CLASS	SUBCLASS	YES	No
AH 0 192 656 B1 05/23/1990 EPO G01B 11/06 AI WO 00/72093 A1 11/30/2000 PCT G03F 9/00	 AG	62157295	06/23/1987	Japan	HOIL			1
Al WO 00/72093 A1 11/30/2000 PCT G03F 9/00	AH	0 192 656 B1	05/23/1990	EPO			1	<del>                                     </del>
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	AK	C.C. Raum et al. "Southernment & Day and Dale II".
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Examiner	Date Considered
Examiner: Initial if citation considered, whether or not citation is in c not in conformance and not considered. Include copy of this form wit	conformance with MPEP Section 609; Draw line through citation if h next communication to applicant.

Modified Form PTO-A820 (also form PTO-1449)

	Docket Number (Optional) TWI-30400	Application Number 10/074.561	
INFORMATION DISCLOSURE CITATION	Applicant(s)		-
(Use several sheets if necessary)	Abdurrahman Sezginer et al.		
	Filing Date	Group Art Unit	-
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Sheet 2 of 2